NSN 5961-01-294-5795

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View Online at https://aerobasegroup.com/nsn/5961-01-294-5795 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.209 inches and 0.230 inches **Function For Which Designed:** Switching **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -60.0 collector to base voltage/static/emitter open and -60.0 collector to emitter voltage/static/base open and -5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 600.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 1.8 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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